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| <b>Notice of References Cited</b> | Application/Control No.<br>10/585,245 |  | Applicant(s)/Patent Under<br>Reexamination<br>KASAMA ET AL. |             |
|                                   | Examiner<br>MARIANNE L. PADGETT       |  | Art Unit<br>1792                                            | Page 1 of 2 |

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